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SD103AWS, SD103BWS, SD103CWS

Vishay Semiconductors

Small Signal Schottky Diodes



MECHANICAL DATA

Case: SOD-323

Weight: approx. 4.3 mg
Packaging codes/options:

18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

FEATURES

 The SD103 series is a metal-on-silicon Schottky barrier device which is protected by a PN junction guard ring



 The low forward voltage drop and fast switching make it ideal for protection of MOS devices, steering, biasing, and coupling diodes for fast switching and low logic level applications



- For general purpose applications
- AEC-Q101 qualified available
- Base P/N-E3 RoHS-compliant, commercial grade
- Base P/N-HE3 RoHS-compliant, AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

PARTS TABLE					
PART	ORDERING CODE	INTERNAL CONSTRUCTION	TYPE MARKING	REMARKS	
SD103AWS	SD103AWS-E3-08 or SD103AWS-E3-18	Cinalo diodo	S6	Tape and reel	
	SD103AWS-HE3-08 or SD103AWS-HE3-18	Single diode	30		
SD103BWS	SD103BWS-E3-08 or SD103BWS-E3-18	Cinalo diodo	S7		
	SD103BWS-HE3-08 or SD103BWS-HE3-18	Single diode	51		
SD103CWS	SD103CWS-E3-08 or SD103CWS-E3-18	Cinalo diodo	S8		
	SD103CWS-HE3-08 or SD103CWS-HE3-18	Single diode	30		

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT	
Repetitive peak reverse voltage		SD103AWS	V_{RRM}	40	V	
		SD103BWS	V_{RRM}	30	V	
		SD103CWS	V_{RRM}	20	V	
Forward continuous current (1)			I _F	350	mA	
Power dissipation (1)			P _{tot}	200	mW	
Single cycle surge	10 μs square wave		I _{FS;M}	2	Α	

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Thermal resistance junction to ambient air (1)		R _{thJA}	500	K/W		
Junction temperature		T _j	125	°C		
Operating temperature range		T _{op}	-55 to +125	°C		
Storage temperature range		T _{stg}	-55 to +150	°C		

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Leakage current	V _R = 30 V	SD103AWS	I _R			5	μA
	V _R = 20 V	SD103BWS	I _R			5	μA
	V _R = 10 V	SD103CWS	I _R			5	μA
Forward voltage drop	I _F = 20 mA		V_{F}			370	mV
	I _F = 200 mA		V_{F}			600	mV
Diode capacitance	V _R = 0 V, f = 1 MHz		C _D		50		pF
Reverse recovery time	$I_F = I_R = 50$ mA to 200 mA, recover to 0.1 I_R		t _{rr}		10		ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

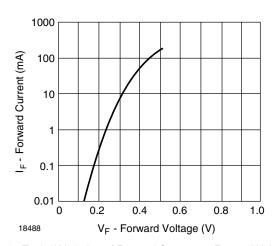


Fig. 1 - Typical Variation of Forward Current vs. Forward Voltage

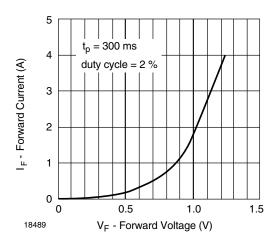


Fig. 2 - Typical High Current Forward Conduction Curve

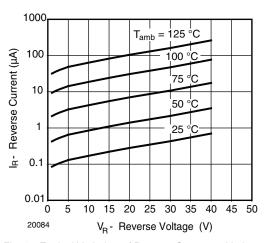


Fig. 3 - Typical Variation of Reverse Current at Various Temperatures

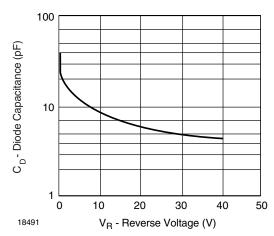


Fig. 4 - Diode Capacitance vs. Reverse Voltage

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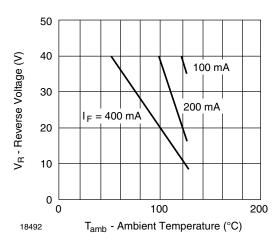
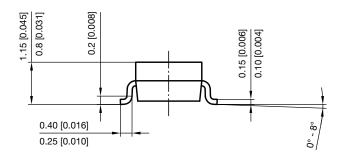
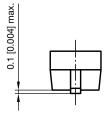
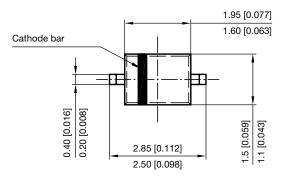


Fig. 5 - Blocking Voltage Deration vs. Temperature at Various Average Forward Currents

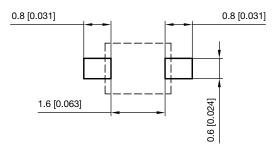
PACKAGE DIMENSIONS in millimeters (inches): SOD-323







Footprint recommendation:



Document no.: S8-V-3910.02-001 (4) Created - Date: 24.August.2004 Rev. 6 - Date: 23.Sept.2016

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